NSN 5961-01-413-6282

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Inclosure Material:
Glass
Mounting Method:
Terminal
Voltage Rating In Volts Per Characteristic:
100.0 reverse voltage, instantaneous
Power Rating Per Characteristic:
500.0 milliwatts any acceptable absolute
Capacitance Rating In Picofarads:
1.2
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0